



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Shunpei Yamazaki et al Art Unit : 2825
 Serial No. : 09/894,950 Examiner : Caridad Everhart
 Filed : June 27, 2001 Confirmation No.: 6263
 Title : SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD
 THEREOF

MAIL STOP AMENDMENT

Commissioner for Patents
 P.O. Box 1450
 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Applicants request consideration of the references listed on the attached PTO-1449 form. Under 37 C.F.R. § 1.98 (a)(2)(ii), only copies of foreign patent documents and/or non-patent literature are enclosed. Copies of any listed U.S. patents or U.S. patent application publications can be provided upon request.

Submitted herewith is an English translation of the following foreign language references, or portions thereof:

Desig. ID	Source
AK	JAPAN 09-043639 – English Abstract: DIALOG(R)File 347:JAPIO (2002); Accession No. 05428839 and family to U.S. Patent No. 5,818,552 (Desig. ID “AA”), U.S. Patent No. 6,067,131 (Desig. ID “AC”) and European Patent Publication No. EP 0 762 180 (Desig. ID “AP)
AL	JAPAN 10-189999 – English Abstract: DIALOG(R)File 347:JAPIO (2002); Accession No. 05906899
AM	JAPAN 11-087726 – full English language translation
AN	JAPAN 59-121876 – full English language translation

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Attorney's Docket No.: 07977-280001 / US5027

This statement is being filed before the receipt of a first Office Action on the merits after the filing of a request for continued examination. No fee is believed to be due. Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: 8/30/05



John F. Hayden
Reg. No. 37,640

Customer No. 26171
Fish & Richardson P.C.
1425 K Street, N.W., 11th Floor
Washington, DC 20005-3500
Telephone: (202) 783-5070
Facsimile: (202) 783-2331

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U.S. Department of Commerce
Patent and Trademark Office

Attorney's Docket No.

07977-280001

Application No.

09/894,950

**Information Disclosure Statement
by Applicant**

(Use several sheets if necessary)

(37 CFR § 1.98(b))

Applicant

Shunpei Yamazaki et al

Filing Date

June 27, 2001

Group Art Unit

2825

U.S. Patent Documents

Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA	5,818,552	10/06/1998	Sato			07/30/1996
	AB	5,889,302	03/30/1999	Liu			04/21/1997
	AC	6,067,131	05/23/2000	Sato			05/29/1998
	AD	6,252,248 B1	06/26/2001	Sano et al.			06/07/1999
	AE	6,380,561 B1	04/30/2002	Ohtani et al.			04/13/1999
	AF	6,576,926 B1	06/10/2003	Yamazaki et al.			02/22/2000
	AG						
	AH						
	AI						
	AJ						

Foreign Patent Documents or Published Foreign Patent Applications

Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AK	09-043639	02/14/1997	JAPAN			AB	
	AL	10-189999	07/21/1998	JAPAN			AB	
	AM	11-087726	03/30/1999	JAPAN			Full	
	AN	59-121876	07/14/1984	JAPAN			Full	
	AO	EP 0 450 941 A2	10/09/1991	EUROPE			In English	
	AP	EP 0 762 180 A1	03/12/1997	EUROPE			In English	

Other Documents (include Author, Title, Date, and Place of Publication)

Examiner Initial	Desig. ID	Document
	AQ	Hirai et al.; "A High-Aperture-Ratio a-Si TFT Liquid Crystal Light Valve for Workstations"; <i>NEC Research & Development</i> 35, No. 2; pp. 165-170; 04/1994
	AR	Kumar et al.; "Kink-free Polycrystalline Silicon Double-Gate Elevated-Channel Thin-Film Transistors"; <i>IEEE Transactions on Electron Devices</i> , Vol. 45, No. 1; pp. 2514-2520; 12/1998
	AS	Yoo et al.; "Pixel Design for TFT-LCD with Double Gate Poly-Si TFT and Double Valve Layer Storage Capacitor"; School of Electrical Engineering, Seoul National University, Seoul, KOREA, Samsung Electronics Co., Ltd.; <i>Proceedings of the Fourth Asian Symposium on Information Display</i> ; pp. 219-222; 1997

Examiner Signature

Date Considered

EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.